LISTING OF CLAIMS:

10/537752 JC17 Rec'd PCT/PTO 06 JUN 2005

This listing of claims will replace all prior versions and listings of claims in the application:

1. (Currently amended) A process for producing a borate-containing, low-alkali material, comprising:

in which induction-heating a boron-containing melting material is induction heated directly in an appliance using an alternating electromagnetic field, and in which wherein the boron-containing melting material includes as a constituent at least one metal oxide, the having metal ions of which have with a valency of at least two, the at least one metal oxide being in a quantitative proportion of at least 25 mol%, and in which the boron-containing melting material having a ratio of the molar substance quantities of silicon dioxide to borate in the melting material is of less than or equal to 0.5.

- 2. (Currently amended) The process as claimed in claim 1, characterized in that the melt is induction-heated directly using wherein the alternating electromagnetic field is a high-frequency field.
- 3. (Currently amended) The process as claimed in claim 1 [[or 2]], eharacterized in that the melt is induction-heated directly using an wherein the alternating electromagnetic field with has a frequency in the range from 50 kHz to 1500 kHz.
- 4. (Currently amended) The process as claimed in one of the preceding claims, characterized in that claim 1, wherein the borateboron-containing, low-alkali melting material comprises a borate-containing material, a borate glass, or a borosilicate glass with a high boric acid content.
- 5. (Currently amended) The process as claimed in one of the preceding claims characterized in that the quantitative proportion of alkali-containing compounds in claim 1, wherein the boron-containing melting material comprises a quantitative proportion of alkali-containing compounds of is less than 2%, preferably less than 0.5%.

- 6. (Currently amended) The process as claimed in one of the preceding claims, characterized in that claim 1, wherein the appliance comprises a skull crucible in which the boron-containing melting material is melted.
- 7. (Currently amended) The process as claimed in claim 6, in which wherein the melting material is melted in a skull crucible has [[, the]] walls of which that comprises cooled tubes which that are spaced apart from one another in such a way that the tube walls adopt by a spacing of between 2 mm and 4 mm, preferably of 2.5 mm to 3.5 mm.
- 8. (Currently amended) The process as claimed in claim [[6 or]] 7, characterized in that wherein the cooled tubes of the skull crucible are short-circuited in particular in the region of a high-frequency coil for emitting the alternating electromagnetic field.
- 9. (Currently amended) The process as claimed in claim 8, eharacterized in that wherein the cooled tubes are short-circuited at, in each case, one location.
- 10. (Currently amended) The process as claimed in claim 8, characterized in that wherein the cooled tubes are, in each case, short-circuited at their ends.
- 11. (Currently amended) The process as claimed in one of claims 6 to 10, characterized in that claim 7, wherein the cooled tubes comprise tubes made from platinum, a platinum alloy, or aluminum.
- 12. (Currently amended) The process as claimed in one of claims 6 to 11, characterized in that claim 7, wherein the cooled tubes of the skull crucible are coated with a layer of platinum or a platinum alloy.
- 13. (Currently amended) The process as claimed in one of claims 6 to 12, characterized in that claim 7, wherein the cooled tubes of the skull crucible are coated with plastic, in particular with fluorine-containing plastic.

- 14. (Currently amended) The process as claimed in one of the preceding claims, eharacterized in that claim 1, further comprising adding a batch is added in the form of pellets to the appliance.
- 15. (Currently amended) The process as claimed in one of the preceding claims, characterized in that the melt is stirred while the batch is being melted down claim 1, further comprising stirring the boron-containing melting material during the induction-heating.
- 16. (Currently amended) The process as claimed in one of the preceding claims, characterized in that claim 1, further comprising blowing a gas is blown into the melt the boron-containing melting material.
- 17. (Currently amended) The process as claimed in claim [[15 or]] 16, characterized in that further comprising introducing a bubbling tube is introduced into the melt boron-containing melting material and blowing the [[a]] gas is blown into the melt boron-containing melting material through a nozzle of the bubbling tube.
- 18. (Currently amended) The process as claimed in one of the preceding claims, characterized in that claim 1, further comprising refining the boron-containing melting material is refined.
- 19. (Currently amended) The process as claimed in claim 18, characterized in that the batch wherein the boron-containing melting material is melted and refined in at least two appliances connected in series.
- 20. (Currently amended) The process as claimed in claim 18, characterized in that batch wherein the boron-containing melting material is melted and refined in the same appliance.
- 21. (Currently amended) The process as claimed in one of the preceding claims, characterized in that claim 1, further comprising discontinuously melting the boron-containing melting material is melted discontinuously in the appliance.

- 22. (Currently amended) The process as claimed in one of the preceding claims, characterized in that claim 1, further comprising continuously melting the boron-containing melting material is melted continuously in the appliance.
- 23. (Currently amended) The process as claimed in one of the preceding claims, characterized in that the A melting material has a composition in which for producing a borate-containing, low-alkali material, comprising:

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\begin{split} &B_2O_3 \ 15 \ to \ 75 \ mol\%, \\ &SiO_2 \ 0 \ to \ 40 \ mol\%, \\ &Al_2O_3, \ Ga_2O_3, \ In_2O_3 \ 0 \ to \ 25 \ mol\%, \\ &\Sigma M(II)O_1M_2(III)O_3 \ 15 \ to \ 85 \ mol\%, \\ &\Sigma M(IV)O_2,M_2(V)O_5,M(VI)O_3 \ 0 \ to \ 20 \ mol\%, \ and \\ &\Sigma M(I)_2O \ \underline{is} \ [[<]] \ \underline{less \ than} \ 0.50 \ mol\% \ \underline{are \ present}, \ and \ \underline{in \ which} \ \underline{wherein} \\ &X(B_2O_3) \ is \ [[>]] \ \underline{greater \ than} \ 0.50, \ where \\ &X(B_2O_3) = B_2O_3/(B_2O_3 + SiO_2), \\ &M(I) = Li, \ Na, \ K, \ Rb, \ Cs, \\ &M(II) = Mg, \ Ca, \ Sr, \ Ba, \ Zn, \ Cd, \ Pb, \ Cu, \\ &M(III) = Sc, \ Y, \ {}^{57}La-{}^{71}Lu, \ Bi, \\ &M(IV) = Ti, \ Zr, \ Hf, \\ &M(V) = Nb, \ Ta, \ \underline{and} \\ &M(VI) = Mo, \ W. \end{split}
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- 24. (Currently amended) The process melting material as claimed in claim 23, characterized in that wherein the B_2O_3 content in the melting material is from 15 to 75 mol% and $X(B_2O_3)$ is [[>]] greater than 0.52.
- 25. (Currently amended) The process melting material as claimed in claim 23, wherein or 24, in which in the melting material the content of

 B_2O_3 is 20 to 70 mol%, the content of $\Sigma M(II)O_3M_2(III)O_3$ is 15 to 80 mol%, and $X(B_2O_3)$ is [[>]] greater than 0.55. 26. (Currently amended) The process melting material as claimed in one of claims 23 to 25, characterized in that in the melting material the content of claim 23, wherein

 B_2O_3 is 28 to 70 mol%, the content of $B_2O_3 + SiO_2$ is 50 to 73 mol%, the content of Al_2O_3 , Ga_2O_3 , In_2O_3 is 0 to 10 mol%, and the content of $\Sigma M(II)O_3M_2(III)O_3$ is 27 to 50 mol%, and $X(B_2O_3)$ is [[>]] greater than 0.55.

27. (Currently amended) The process melting material as claimed in claim 26, characterized in that a composition is selected for the melting material in which: wherein

 B_2O_3 is 36 to 66 mol%, SiO_2 is 0 to 40 mol%, $B_2O_3 + SiO_2$ is 55 to 68 mol%, Al_2O_3 , Ga_2O_3 , In_2O_3 is 0 to 2 mol%, $\Sigma M(II)O_3M_2(III)O_3$ is 27 to 40 mol%, $\Sigma M(IV)O_2M_2(V)O_5M(VI)O_3$ is 0 to 15 mol% are present, and $X(B_2O_3)$ is [[>]] greater than 0.65.

28. (Currently amended) The process as claimed in one of the preceding claims, in particular claim 1, wherein the borate-containing, low-alkali material is useful for the production of borate glasses and borosilicate glasses with a high boric acid content for optical applications, characterized in that the boron-containing melting material has the following composition comprising:

 B_2O_3 45 to 66 mol%, SiO_2 0 to 12 mol%, $B_2O_3 + SiO_2$ 55 to 68 mol%, Al_2O_3 , Ga_2O_3 , In_2O_3 0 to 0.5 mol%, $\Sigma M(II)O$ 0 to 40 mol%, $\Sigma M_2(III)O_3$ 0 to 27 mol%, $\Sigma M(II)O_3M_2(III)O_3$ 27 to 40 mol%, $\Sigma M(IV)O_2,M_2(V)O_5,M(VI)O_3$ 0 to 15 mol%, and in which wherein $X(B_2O_3)$ is [[>]] greater than 0.78, where M(II) = Mg, Ca, Sr, Ba, Zn, Cd, Pb.

29. (Currently amended) The process as claimed in one of the preceding claims, in particular claim 1, wherein the borate-containing, low-alkali material is useful for the production of borate glasses and crystallizing boron-containing materials, characterized in that the boron-containing melting material has a composition in which the following contents are present comprising:

 $B_2O_3 \quad 30 \text{ to } 75 \text{ mol\%},$ $SiO_2 \quad [[<]] \; \underline{less \; than} \; 1 \; mol\%,$ $Al_2O_3, \; Ga_2O_3, \; In_2O_3 \quad 0 \; to \; 25 \; mol\%,$ $\Sigma M(II)O, M_2(III)O_3 \; 20 \; to \; 85 \; mol\%, \; and$ $\Sigma M(IV)O_2, M_2(V)O_5, M(VI)O_3 \; 0 \; to \; 20 \; mol\%, \; and \; \underline{in \; which \; wherein}$ $X(B_2O_3) \; is \; [[>]] \; \underline{greater \; than} \; 0.90.$

30. (Currently amended) The process as claimed in one of the preceding claims, in particular claim 1, wherein the borate-containing, low-alkali material is useful for producing crystallizing borate-containing material, wherein the boron-containing melting material has a composition in which comprising:

 B_2O_3 20 to 50 mol%, $SiO_2 = 0 \text{ to } 40 \text{ mol\%},$ $Al_2O_3, Ga_2O_3, In_2O_3 = 0 \text{ to } 25 \text{ mol\%},$ $\Sigma M(II)O, M_2(III)O_3 = 15 \text{ to } 80 \text{ mol\%}, \text{ and}$ $\Sigma M(IV)O_2, M_2(V)O_5, M(VI)O_3 = 0 \text{ to } 20 \text{ mol\%}, \text{ are present, and in which wherein}$ $X(B_2O_3) \text{ is } [[>]] \text{ greater than } 0.52.$

- 31. (Currently amended) The process as claimed in claim 30, characterized in that wherein X(B₂O₃) is [[>]] greater than 0.55.
- 32. (Currently amended) The process as claimed in claim 30 or 31, characterized in that, wherein the quantitative proportions are

 Σ M(II)O 15 to 80 mol%, and M_2 (III)O₃ 0 to 5 mol%, and $X(B_2O_3)$ is [[>]] greater than 0.60.

- 33. (Currently amended) The process as claimed in one of claims 30 to 32, characterized in that claim 30, wherein the quantitative proportion of substances selected from a group consisting of Al₂O₃, Ga₂O₃ and In₂O₃ does not exceed 5 mol%.
- 34. (Currently amended) The process as claimed in one of claims 30 to 33, characterized in that the composition for the melting material is selected in such a way that claim 30, wherein the quantitative proportion of substances selected from a group consisting of Al_2O_3 , Ga_2O_3 and In_2O_3 does not exceed 3 mol%, and in which the quantitative proportion of $\Sigma M(II)O$ is in the range from 15 to 80 mol%, and in which $X(B_2O_3)$ is [[>]] greater than 0.65, where M(II) = Zn, Pb, Cu.

35. (Currently amended) The process as claimed in one of the preceding claims, characterized in that a composition is selected for claim 1, wherein the boron-containing melting material in which comprises:

 B_2O_3 20 to 50 mol%, SiO_2 0 to 40 mol%, Al_2O_3 0 to 3 mol%, ΣZnO , PbO, CuO 15 to 80 mol%, Bi_2O_3 0 to 1 mol%, and $\Sigma M(IV)O_2,M_2(V)O_5,M(VI)O_3$ 0 to 0.5 mol% are present, and in which wherein $X(B_2O_3)$ is [[>]] greater than 0.65.

36. (Currently amended) The process as claimed in claim 35, characterized in that a composition is selected for the melting material in which the quantities of substance are wherein a substance are wherein the substance are substance a

 B_2O_3 <u>is</u> 20 to 42 mol%, SiO_2 <u>is</u> 0 to 38 mol%, ΣZnO , PbO <u>is</u> 20 to 68 mol%, CuO <u>is</u> 0 to 10 mol%, ΣZnO , PbO, CuO <u>is</u> 20 to 68 mol%, and Bi_2O_3 <u>is</u> 0 to 0.1 mol%, and in which wherein $X(B_2O_3)$ is [[>]] greater than 0.65.

37. (Currently amended) The process as claimed in one of claims 1 to 36, a composition which claim 1, wherein the boron-containing melting material is free of PbO and CdO is selected for the melting material.